

FEATURES

- Supply voltages from 3 V to 5.5V
- Dual-channel
- 120kbps Data Rates
- 15kV HBM ESD-Protected
- 8kV IEC-4100-4-2 Contact Discharge

OUTLINE

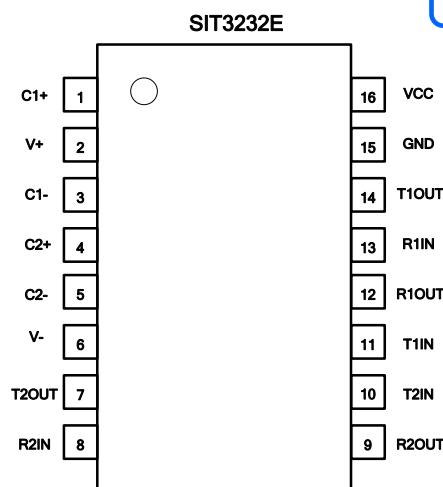
Provide green and environmentally friendly lead-free package

DESCRIPTION

SIT3232E is a 3.3V-power-supply, dual-channel,high ESD-protected, low-power RS-232 transceiver that fully meets the requirements of the TIA/EIA-232 standard.

SIT3232E includes two drives and two receivers,with enhanced ESD protection function, reaching the protection capacity of HBM ESD above 15kV and 8kV IEC-4100-4-2 contact discharge.

Powered by 3.3V power supply, The charge pump requires only four 1 μ F external capacitance to work at a rate of at least 120Kbps error-free data transmission, both of which can be independently enabled and closed. Each driver and receiver can be used independently.

PIN CONFIGURATION

LIMITING VALUES

PARAMETER	SYMBOL	VALUE	UNIT
Supply voltage	VCC	-0.3~+6	V
Doubled Voltage Terminal	V+	VCC-0.3~+7	V
Inverted Voltage Terminal	V-	+0.3~-7	V
V+ + V-		+13	V
Transmitter Input Voltage Range	T1IN,T2IN	-0.3~+6	V
Receiver Input Voltage Range	R1IN,R2IN	±25	V
Transmitter Output Voltage Range	T1OUT,T2OUT	±13.2	V
Receiver Output Voltage Range	R1OUT,R2OUT	-0.3~VCC+0.3	V
Operating Temperature		-40~85	°C
Storage Temperature		-60~150	°C
Soldering Temperature		300	°C
Continuous Power	SOP16	760	mW
	DIP16	840	mW

The maximum limit parameters means that exceeding these values may cause irreversible damage to the device. Under these conditions, it is not conducive to the normal operation of the device. The continuous operation of the device at the maximum allowable rating may affect the reliability of the device. The reference point for all voltages is ground.

PINNING

PIN	SYMBOL	DESCRIPTION
1	C1+	Positive Terminal for the first Charge Pump Capacitor
2	V+	Doubled Voltage Terminal
3	C1-	Negative Terminal for the first Charge Pump Capacitor
4	C2+	Positive Terminal for the second Charge Pump Capacitor
5	C2-	Negative Terminal for the second Charge Pump Capacitor
6	V-	Inverted Voltage Terminal
7	T2OUT	Second Transmitter Output Voltage

8	R2IN	Second Receiver Input Voltage
9	R2OUT	Second Receiver Output Voltage
10	T2IN	Second Transmitter Input Voltage
11	T1IN	First Transmitter Input Voltage
12	R1OUT	First Receiver Output Voltage
13	R1IN	First Receiver Input Voltage
14	T1OUT	First Transmitter Output Voltage
15	GND	Ground
16	VCC	Supply Voltage

Supply Current

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current with no Load	I_{sup}			2		mA

(If there is no additional explanation,typical value is tested when VCC=+3.3V,Temp=25 °C,C1-C4=1μF)

Logic Input Electrical Characteristics

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Logic Control Low Level	VT_{TIN_L}	T1IN,T2IN			0.8	V
Logic Control High Level	VT_{TIN_H}	T1IN,T2IN	2			V
Logic Control Hysteresis		T1IN,T2IN		0.3		V
Input Logic Current	$ITIN$	T1IN,T2IN			±1	μA

(If there is no additional explanation,typical value is tested when VCC=+3.3V,Temp=25 °C,C1-C4=1μF)

Receiver Output Electrical Characteristics

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Receiver Output Logic-Low Voltage	V_{ROL}	$I_{OUT}=1.6mA$, VCC=5V or 3.3V			0.4	V



Receiver Output Logic-High Voltage	V _{ROH}	I _{OUT} =-0.5mA, VCC=5V or 3.3V	VCC-0.6	VCC-0.1		V
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(If there is no additional explanation,typical value is tested when VCC=+3.3V,Temp=25 °C,C1-C4=1μF)

Receiver Input Electrical Characteristics

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Receiver Input Range	V _{RIN}		-25		+25	V
Receiver Input Low Threshold	V _{RIL}	VCC=3.3V	0.6	1.1		V
		VCC=5V	0.8	1.5		V
Receiver Input High Threshold	V _{RIH}	VCC=3.3V		1.5	2.4	V
		VCC=5V		1.9	2.4	V
Receiver Input Hysteresis				0.4		V
Receiver Input Impedance	R _{RIN}		3	5	7	kΩ

(If there is no additional explanation,typical value is tested when VCC=+3.3V,Temp=25 °C,C1-C4=1μF)

Transmitter Output Electrical Characteristics

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Transmitter Output Swing	V _{TOUT}	All output ports of transmitter connect 3kΩ load to ground	±4		±5	V
Transmitter Output Impedance	R _{TOUT}	VCC=0V, Transmitter Input=±2V	300			Ω
Transmitter Short-Circuit Current	I _{tsc}				60	mA

(If there is no additional explanation,typical value is tested when VCC=+3.3V,Temp=25 °C,C1-C4=1μF)

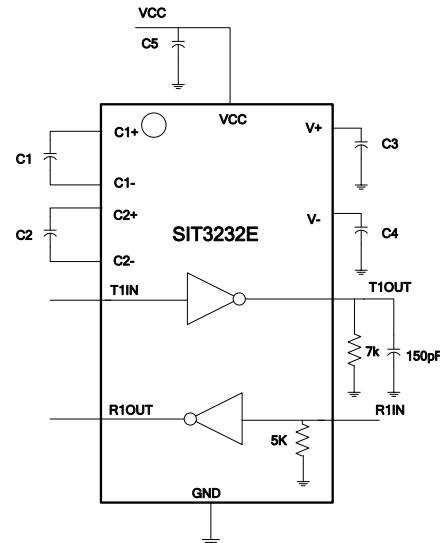
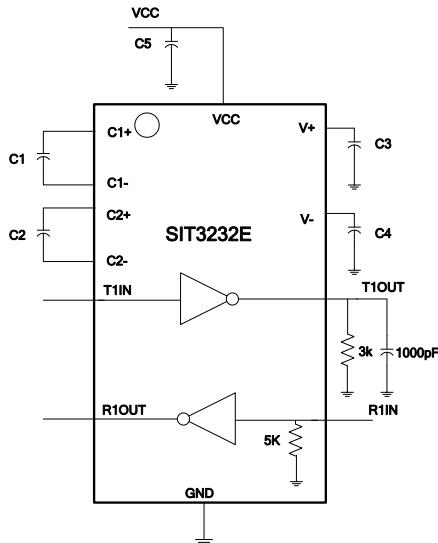
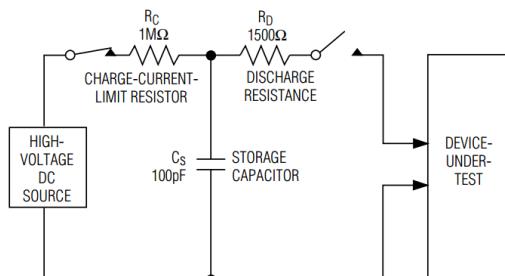
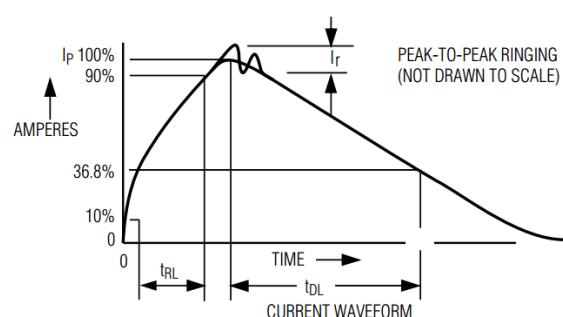
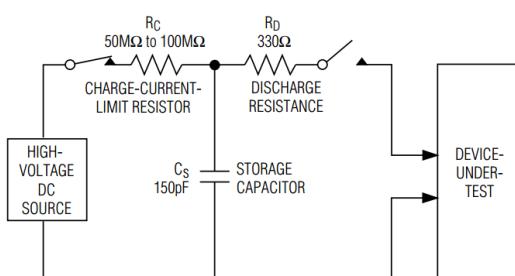
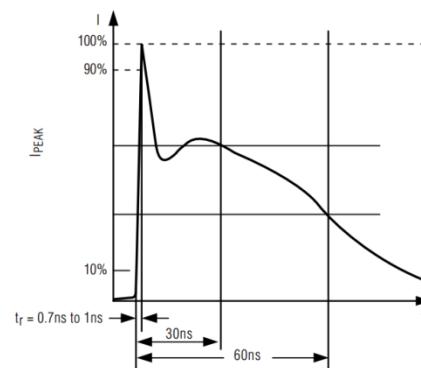
ESD protection

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
R1IN、R2IN T1OUT、T2OUT		HBM		±15		KV
		Air Discharge		±15		KV
		Contact Discharge		±8		KV

Switching Characteristics Parameter

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Rate	Speed	RL=3kΩ, CL=1000pF		120		kbps
Receiver Propagation delay	t _{RPHL}	CL=150pF		300		ns
	t _{RPLH}			300		ns
t _{RPHL} - t _{RPLH}				150		ns
t _{TPHL} - t _{TPLH}				150		ns
Transmitter Slew Rate	SR	RL=3kΩ~7kΩ, CL=150pF~1000pF from -3.0V~3.0V or from 3.0V~-3.0V See figures 2 and 3	4		30	V/μs

(If there is no additional explanation, typical value is tested when VCC=+3.3V, Temp=25 °C, C1-C4=1μF)

TEST CIRCUIT

Figure 2 minimum swing rate test circuit
Figure 3 maximum swing rate test circuit

Figure 4 ESD test model of human body mode

Figure 5 human body mode current waveform

Figure 6 ESD test model of IEC 1000-4-2

Figure 7 current waveform of IEC 1000-4-2 ESD

ADDITIONAL DESCRIPTION

1 Dual Charge-Pump Operation

SIT3232E has a two-way charge pump inside to support the chip's voltage conversion work. Dual-electric pump provides +5.5V and -5.5V output voltage in the range of 3.0 ~ 5.5V, Each charge pump requires a capacitor(C1,C2) and an energy storage capacitor(C3,C4) to generate V+ and V-power supplies, as shown in Fig 8.

2 RS232 Transmitter

Convert the TTL/CMOS logic voltage to a voltage compatible with the EIA/TIA-232 standard. SIT3232E Transmiter can guarantee 120kbps data rate under the worst operating conditions (Parallel load of $3k\Omega$ resistor and 1000pf capacitor). Transmitter can drive multiple receivers in parallel. There is no pull-up resistance inside the input terminals T1IN and T2IN of SIT3232E transmitter. If the transmitter is not used, the unused input terminals T1IN and T2IN can be connected to GND or VCC.

3 RS232 Receiver

The SIT3232E has two separate receivers that convert the RS-232 signal to the CMOS logic output level.

4 ESD Protection

All pins of SIT3232E adopt ESD protection structure, and all driver outputs and receiver inputs have additional electrostatic protection capability. It can withstand $\pm 15kV$ ESD (HBM) discharge, contact discharge above $\pm 8KV$ and air gap discharge above $\pm 15kV$. The ESD protection structure can withstand the impact of high voltage ESD under all conditions, including standard working mode and power-off mode.

5 Typical Application

Typical dual-Path application scenarios are shown in Figure 8, where the C1-C5 typical capacitance value is $0.1\mu F$.

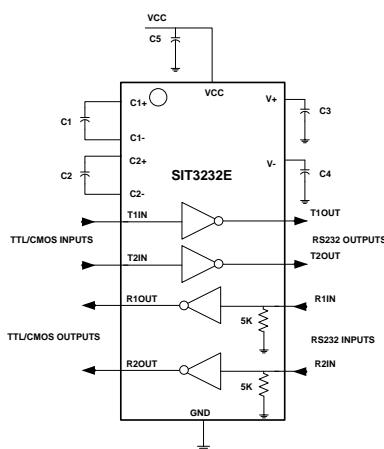
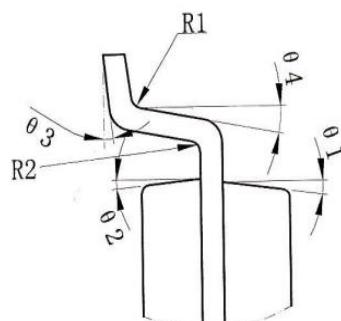
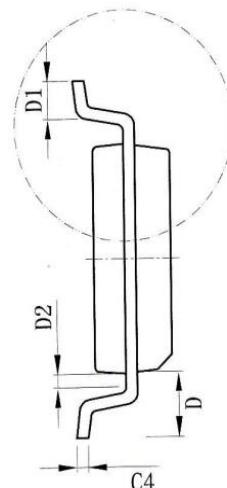
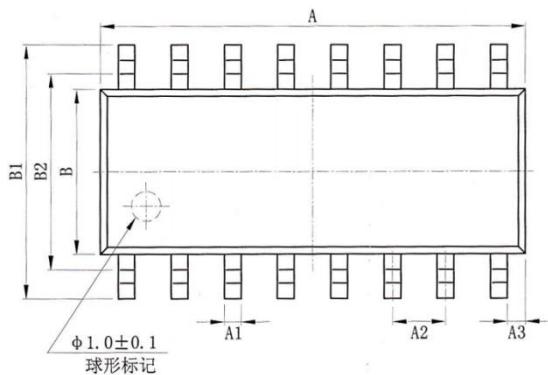
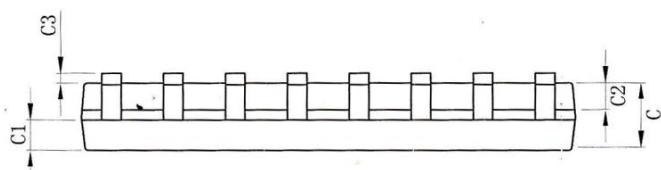


Figure 8 Typical dual-Path application scenarios

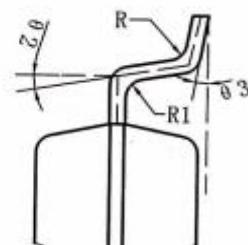
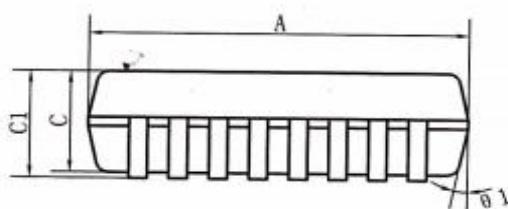
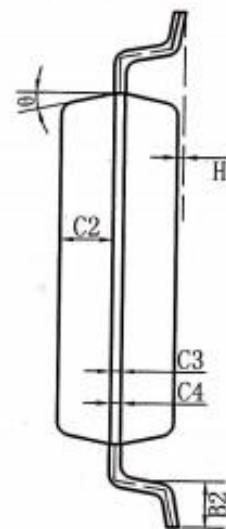
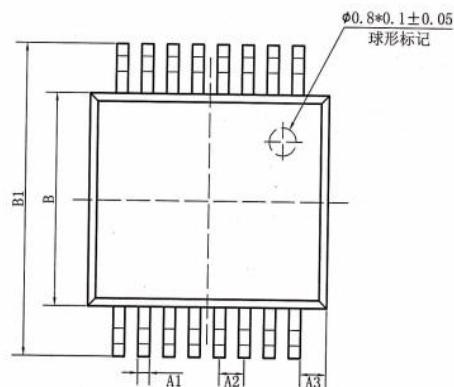
SOP16 DIMENSIONS
PACKAGE SIZE

SIZE SYMBOL	MIN./mm	MAX./mm
A	9.80	10.00
A1	0.356	0.456
A2	1.27TYP	
A3	0.302TYP	
B	3.85	3.95
B1	5.84	6.24
B2	5.00 TYP	
C	1.40	1.60
C1	0.61	0.71
C2	0.54	0.64
C3	0.05	0.25
C4	0.203	0.233
D	1.05 TYP	
D1	0.40	0.70
D2	0.15	0.25
R1	0.20TYP	
R2	0.20TYP	
θ1	8°~12°TYP4	
θ2	8°~12°TYP4	
θ3	0°~8°	
θ4	4°~12°	



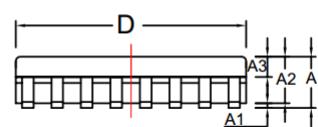
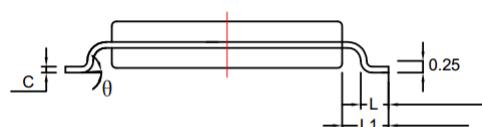
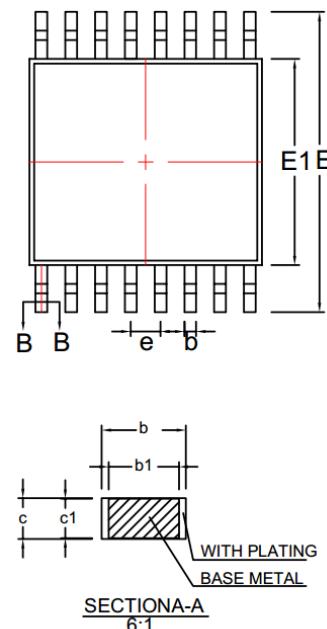
SSOP16(0.65) DIMENSIONS
PACKAGE SIZE

SIZE SYMBOL	MIN/mm	MAX/mm
A	6.15	6.25
A1	0.30TYP	
A2	0.65TYP	
A3	0.675TYP	
B	5.25	5.35
B1	7.65	7.95
B2	0.60	0.80
C	1.70	1.80
C1	1.75	1.95
C2	0.799	
C3	0.152	
C4	0.172	
H	0.05	0.15
θ	12°TYP4	
θ_1	12°TYP4	
θ_2	10°TYP	
θ_3	0°~8°	
R	0.20°TYP	
R	0.15°TYP	



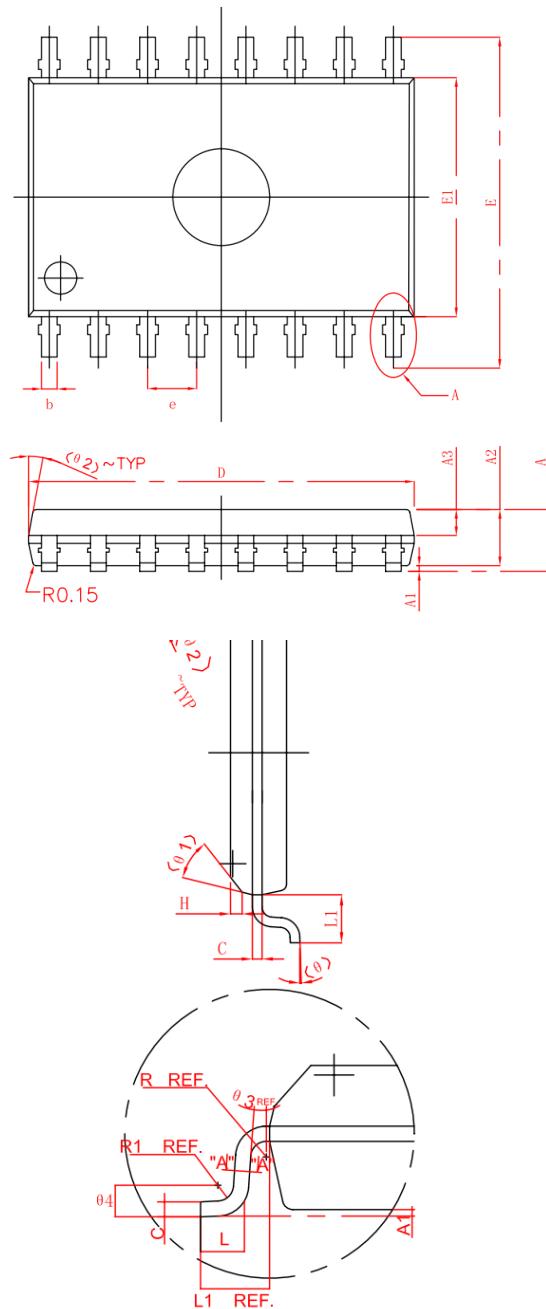
TSSOP16 DIMENSIONS
PACKAGE SIZE

SIZE SYMBOL	MIN./mm	TYP./mm	MAX./mm
A	--	--	1.20
A1	0.05		0.15
A2	0.90	1.00	1.05
b	0.20	--	0.30
b1	0.19	0.22	0.25
c	0.110	0.127	0.145
c1	0.12	0.13	0.14
D	4.86	4.96	5.06
E	6.20	6.40	6.60
E1	4.30	4.40	4.50
e	0.65BSC		
L	0.45	0.60	0.75
L1	1.00BSC		
	0°	--	8°



SOPW16 DIMENSIONS
封装尺寸

标注	尺寸	最小值/mm	最大值/mm
A	-	2.65	
A1	0.10	0.30	
A2	2.25	2.35	
A3	0.97	1.07	
D	10.10	10.50	
E	10.26	10.60	
E1	7.30	7.70	
e		1.27BSC	
L	0.55	0.85	
L1		1.4BSC	
H	0.345	0.365	
R		0.20TYP	
R1		0.30TYP	
θ	0°	8°	
θ_1		45°TYP	
θ_2		12°TYP	
θ_3	0°	8°	
θ_4	0°	10°	





ORDERING INFORMATION

TYPE NUMBER	TEMPERATURE	PACKAGE
SIT3232EESE	-40°C~85°C	SOP16
SIT3232EEAE	-40°C~85°C	SSOP16
SIT3232EEUE	-40°C~85°C	TSSOP16
SIT3232EEWE	-40°C~85°C	WSOP16 Wide body

The tapered package of SIT3232EESE , SIT3232EEUE is 2500 pieces/disc.